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2SA1943/FJL4215 PNP Epitaxial Silicon Transistor

Applications

- High-Fidelity Audio Output Amplifier
- General Purpose Power Amplifier

Features

- High Current Capability: $I_C = -17A$.
- High Power Dissipation : 150watts.
- High Frequency : 30MHz.
- High Voltage : V_{CEO}= -250V
- Wide S.O.A for reliable operation.
- Excellent Gain Linearity for low THD.
- Complement to 2SC5200/FJL4315.
- Full thermal and electrical Spice models are available.
- Same transistor is also available in:
- -- TO3P package, 2SA1962/FJA4213 : 130 watts
- -- TO220 package, FJP1943 : 80 watts
- -- TO220F package, FJPF1943 : 50 watts

Absolute Maximum Ratings* T_a = 25°C unless otherwise noted

| Symbol | Parameter | Ratings | Units | |
|-----------------------------------|---|-------------|-----------|--|
| BV _{CBO} | Collector-Base Voltage | -250 | V | |
| BV _{CEO} | Collector-Emitter Voltage | -250 | V | |
| BV _{EBO} | Emitter-Base Voltage | -5 | V | |
| I _C | Collector Current | -17 | А | |
| I _B | Base Current | -1.5 | А | |
| P _D | Total Device Dissipation(T _C =25°C) Derate above 25°C | 150 1.04 | W W/°C | |
| T _J , T _{STG} | Junction and Storage Temperature | - 50 ~ +150 | °C | |

* These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

$\label{eq:thermal} Thermal \ Characteristics^* \quad {}_{T_a=25^\circ C} \ {}_{unless \ otherwise \ noted}$

| Symbol | Parameter | Max. | Units | |
|---------------------|--------------------------------------|------|-------|--|
| $R_{	ext{	heta}JC}$ | Thermal Resistance, Junction to Case | 0.83 | °C/W | |

* Device mounted on minimum pad size

h_{FE} Classification

| Classification | R | 0 |
|------------------|----------|----------|
| h _{FE1} | 55 ~ 110 | 80 ~ 160 |

1 TO-264 1.Base 2.Collector 3.Emitter

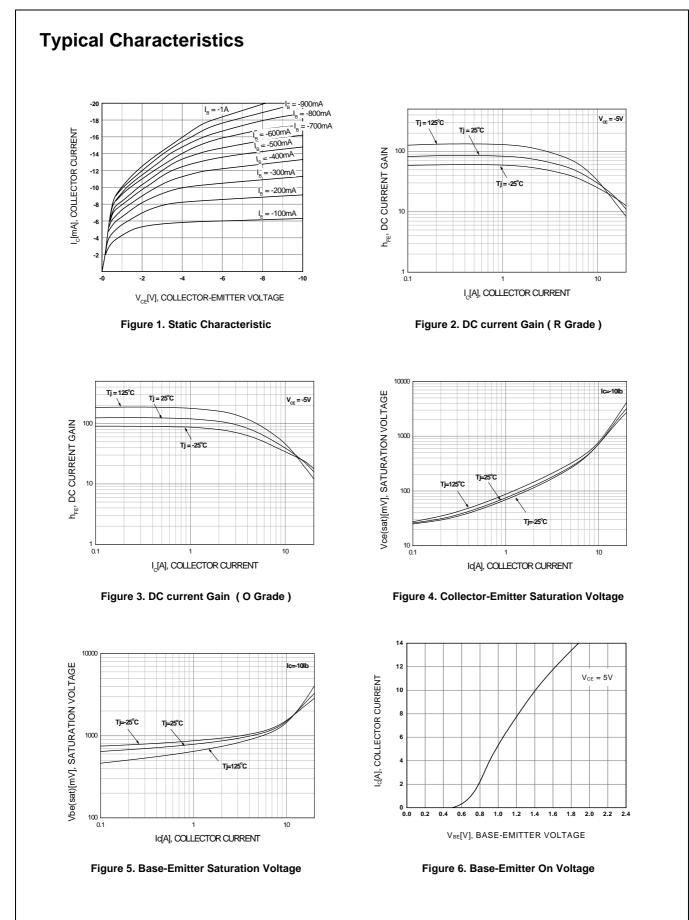
January 2009

| Symbol | Parameter | Test Condition | Min. | Тур. | Max. | Units |
|-----------------------|--------------------------------------|--|------|------|------|-------|
| BV _{CBO} | Collector-Base Breakdown Voltage | I _C =-5mA, I _E =0 | -250 | | | V |
| BV _{CEO} | Collector-Emitter Breakdown Voltage | I_C =-10mA, R_{BE} = ∞ | -250 | | | V |
| BV _{EBO} | Emitter-Base Breakdown Voltage | I _E =-5mA, I _C =0 | -5 | | | V |
| I _{CBO} | Collector Cut-off Current | V _{CB} =-230V, I _E =0 | | | -5.0 | μA |
| I _{EBO} | Emitter Cut-off Current | V_{EB} =-5V, I _C =0 | | | -5.0 | μΑ |
| h _{FE1} | DC Current Gain | V _{CE} =-5V, I _C =-1A | 55 | | 160 | |
| h _{FE2} | DC Current Gain | V _{CE} =-5V, I _C =-7A | 35 | 60 | | |
| V _{CE} (sat) | Collector-Emitter Saturation Voltage | I _C =-8A, I _B =-0.8A | | -0.4 | -3.0 | V |
| V _{BE} (on) | Base-Emitter On Voltage | V _{CE} =-5V, I _C =-7A | | -1.0 | -1.5 | V |
| f _T | Current Gain Bandwidth Product | V _{CE} =-5V, I _C =-1A | | 30 | | MHz |
| C _{ob} | Output Capacitance | V _{CB} =-10V, f=1MHz | | 360 | | pF |

^t Pulse Test: Pulse Width=20µs, Duty Cycle≤2%

Ordering Information

| Part Number | Marking | Package | Packing Method | Remarks |
|-------------|---------|---------|----------------|--------------|
| 2SA1943RTU | A1943R | TO-264 | TUBE | hFE1 R grade |
| 2SA1943OTU | A1943O | TO-264 | TUBE | hFE1 O grade |
| FJL4215RTU | J4215R | TO-264 | TUBE | hFE1 R grade |
| FJL4215OTU | J4215O | TO-264 | TUBE | hFE1 O grade |



Typical Characteristics 100 1.0 Transient Thermal Resistance, $R_{\rm hic} l^{\circ} C \slash W J$ I_c MAX. (Pulsed*) 0.9 I_c [A], COLLECTOR CURRENT 10ms* 0.8 10 I_c Max. (DC) 0.7 100ms 0.6 DC 0.5 0.4 0.3 0.1 0.2 *SINGLE NONREPETITIVE 0.1 PULSE $T_c=25[°C]$ 0.01 1E-6 1E-5 1E-4 1E-3 0.01 0.1 10 100 Pulse duration [sec] V_{CE} [V], COLLECTOR-EMITTER VOLTAGE Figure 7. Thermal Resistance Figure 8. Safe Operating Area

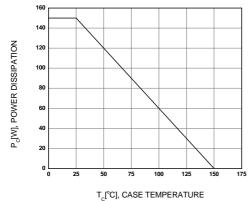
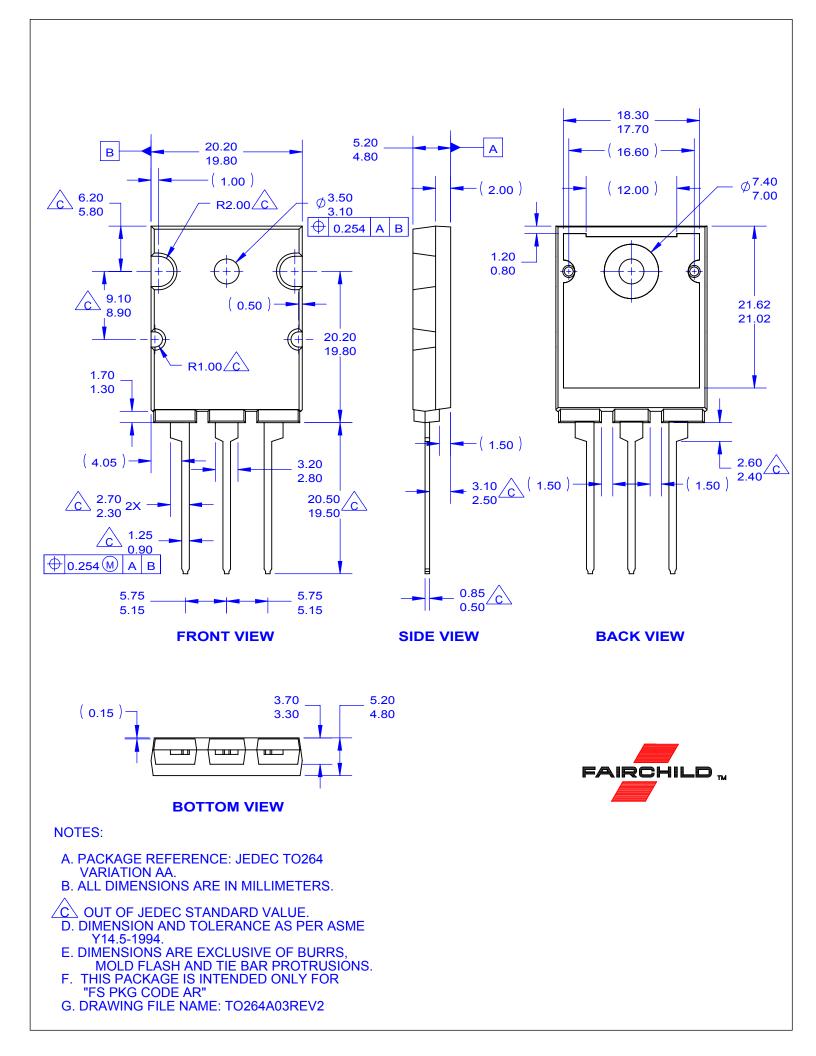


Figure 9. Power Derating



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